

TOSHIBA Transistor Silicon PNP Epitaxial (PCT process)

2SA1588

Audio Frequency Low Power Amplifier Applications

Driver Stage Amplifier Applications

Switching Applications

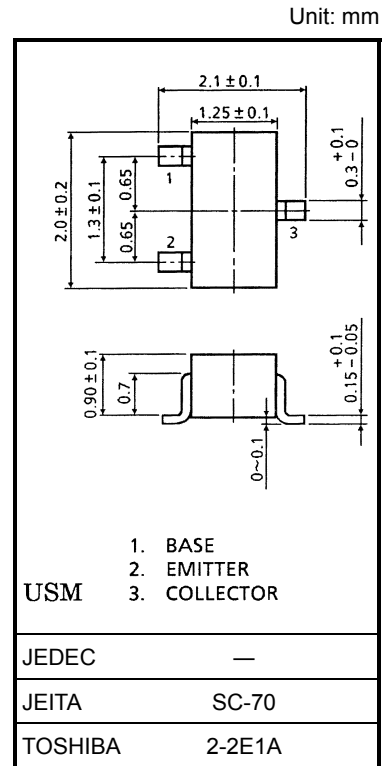
- Excellent hFE linearity: hFE (2) = 25 (min)
at VCE = -6 V, IC = -400 mA
- Complementary to 2SC4118

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	-35	V
Collector-emitter voltage	V _{CEO}	-30	V
Emitter-base voltage	V _{EB0}	-5	V
Collector current	I _C	-500	mA
Base current	I _B	-50	mA
Collector power dissipation	P _C	100	mW
Junction temperature	T _j	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.006 g (typ.)

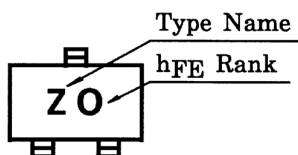
Electrical Characteristics (Ta = 25°C)

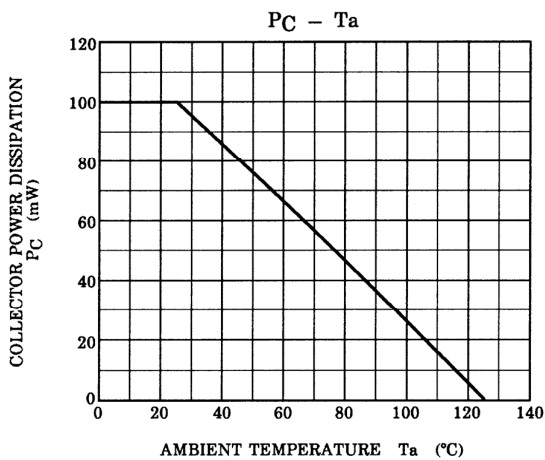
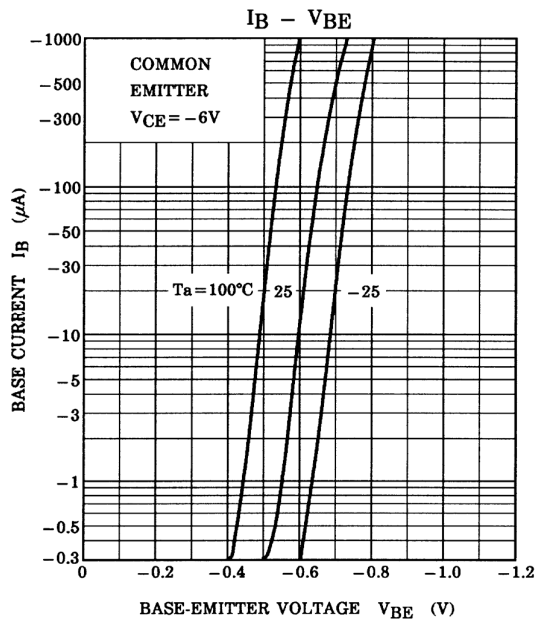
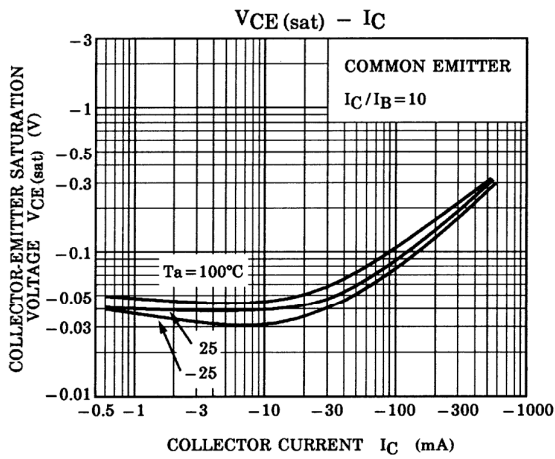
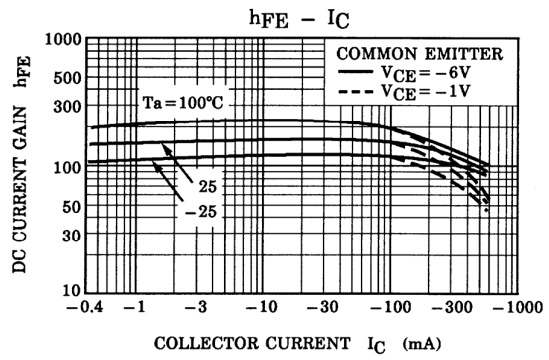
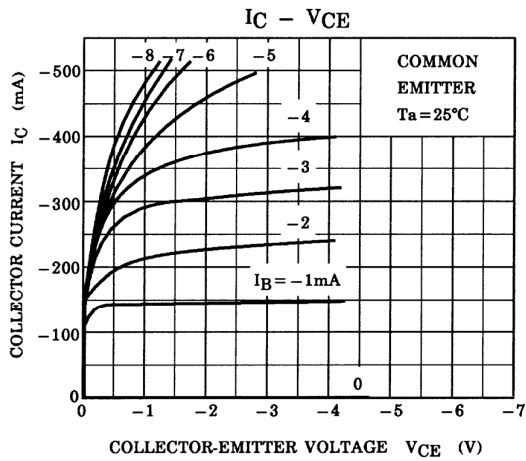
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I _{CB0}	V _{CB} = -35 V, I _E = 0	—	—	-0.1	μA
Emitter cut-off current	I _{EB0}	V _{EB} = -5 V, I _C = 0	—	—	-0.1	μA
DC current gain (Note)	h _{FE} (1)	V _{CE} = -1 V, I _C = -100 mA	70	—	400	
	h _{FE} (2)	V _{CE} = -6 V, I _C = -400 mA	25	—	—	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -100 mA, I _B = -10 mA	—	-0.1	-0.25	V
Base-emitter voltage	V _{BE}	V _{CE} = -1 V, I _C = -100 mA	—	-0.8	-1.0	V
Transition frequency	f _T	V _{CE} = -6 V, I _C = -20 mA	—	200	—	MHz
Collector output capacitance	C _{ob}	V _{CB} = -6 V, I _E = 0, f = 1 MHz	—	13	—	pF

Note: h_{FE} (1) classification O(O): 70~140, Y(Y): 120~240, GR(G): 200~400 () Marking Symbol

h_{FE} (2) classification O: 25 (min), Y: 40 (min), GR: 75 (min)

Marking





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20070701-EN GENERAL

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